IFW



Docket No.: 5232-0102PUS1

(PATENT)

## IN THE ATTED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Hiroaki MATSUMURA et al.

Application No.: 10/563,811

application 100 100 co,c1

Filed: January 9, 2006

For: NITRIDE SEMICONDUCTOR LASER

DEVICE AND LASER APPARATUS USING

THE SAME

Confirmation No.: 1910

Art Unit: N/A

Examiner: Not Yet Assigned

## **LETTER**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Subsequent to the filing of the above-identified application on January 9, 2006, attached hereto is an English translation of the International Preliminary Examination Report (Form PCT/IPEA/409) that should be made of record in the present application.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or to credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; particularly, extension of time fees.

Dated: September 6, 2006

Respectfully súbmitted,

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